Surface sublimation of zinc blende CdTe


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The surface sublimation of Cd and Te atoms from the zinc blende (111) A CdTe surface has been investigated in detail by reflection high energy electron diffraction and x-ray photoelectron spectroscopy. These experiments verify that Te is much easier to evaporate than Cd. The experimental value for the Te activation energy from a Te stabilized (111) A CdTe surface is 1.41 ± 0.10 eV, which is apparently inconsistent with recent theoretical results.

Recently, considerable attention has been paid to the study of surface sublimation of CdTe and HgTe in theoretical1-3 as well as experimental investigations using molecular beam epitaxially (MBE) grown samples.4-6

Many attempts have been made to determine the activation energy for surface sublimation processes in various experiments on CdTe,7,8 GaAs,9,10 ZnSe,11 or compounds containing these materials, but the reported values differ substantially. This may be because different experimental conditions were used. For example, if high energy electrons are used to observe a surface structure in order to measure the sublimation rates of Cd and Te,12 energy changes in the high energy electron diffraction (RHEED) patterns from the concentrated limit to the dilute limit in the literature.3 If we use even more extreme values, i.e., 1040 instead of 1013 for Te and 1027 instead of 1037 for Cd, then K_Cd ≈ 10^2 × K_Te for the (111) A CdTe surface at 230 °C. Therefore, the Cd atomic layer should be easily evaporated, and consequently, the surface should be terminated with Te atoms.

In order to determine whether the calculations of Krishnamurthy et al.1,2 correctly predict sublimation energies for CdTe, the following experiment was carried out under conditions as near as possible to those used in their calculations. Consequently, we determined the activation energy for Cd from a Cd stabilized surface and for Te from a Te stabilized surface, i.e., for the removal of atoms in the concentrated limit.4 We employed (111) A CdTe terminated by either a triply bonded Cd atom or a singly bonded Te atom, as well as Cd and Te stabilized (100) and (111) B CdTe. (111) A CdTe is emphasized in this letter because the theoretical calculations for Si, GaAs, CdTe, and HgTe1,2 predict that the difference between the sublimation energies for the anion and cation is largest for (111) A CdTe. In addition, RHEED patterns for Cd and Te terminated surfaces are easily distinguishable.

Experimental details have been described in previous publications4,5 The substrates employed in this work were (111) A, (111) B, and (100) Cd_{0.96}Zn_{0.04}Te and CdTe. During the following, we kept all ovens at temperatures lower than 100 °C, and the main shutter and every individual oven shutter closed. Thus, no Cd, Te, or CdTe partial pressures were present. The vacuum in the growth chamber during heat treatment was better than 4×10^{-10} Torr. If untreated (111) A Cd_{0.96}Zn_{0.04}Te substrates are kept in the MBE growth chamber at temperatures less than 160 °C, spotty RHEED patterns appeared, which is characteristic of untreated CdTe surfaces. At temperatures as low as 170 °C, the RHEED patterns were still spotty, but clear, integral order streaks were present. This is in con-
contrat to (100) CdTe, where heat treating (100) and (111)B CdTe substrates in vacuum normally results in spotty RHEED patterns initially, and then, in modulated integral order and sometimes half-order reconstruction streaks when the substrate temperature is slowly increased up to 250°C. Only smooth streaks are visible if the substrate is held at 180°C or higher for about 15 min. Here, (1×1) reconstruction persists for several tens of seconds, and then (2×2) reconstruction appears. This (2×2) reconstruction becomes stronger for several minutes before reaching saturation. The original (1×1) reconstruction can never be recovered by heating at any temperature without an additional Te flux. (1×1) reconstruction indicates a Te stabilized surface and (2×2) reconstruction a Cd stabilized surface for the (111)A CdTe surface, as discussed below. As is well known, CdTe and Cd$_{0.96}$Zn$_{0.04}$Te surfaces which have been polished with a solution of Br in methanol and/or etched in dilute HCl always contain much more Te than Cd.\textsuperscript{13,14} Thus, Te is preferentially evaporated by this heat treatment. X-ray photoelectron spectroscopy (XPS) measurements of this surface also indicated that the untreated surface was Te rich, i.e., contained more than one atomic layer of Te, but that after heat treatment at about 180°C, the surface was Cd terminated. This was accomplished by means of our calibrated atomic sensitivity factors.\textsuperscript{4} We have also heat treated a MBE grown CdTe film on a (111)A Cd$_{0.96}$Zn$_{0.04}$Te substrate and observed (2×2) reconstruction.

The RHEED pattern during the growth of (111)A CdTe at 330°C displays a very distinct (2×2) reconstruction. The strength of this reconstruction could be reduced by lowering the substrate temperature and it would eventually become (1×1) during growth when the substrate temperature reached approximately 100°C. The CdTe flux was between 3 and 4×10$^{-7}$ Torr. This result indicates that the Te sticking coefficient is much larger than that of Cd since (1×1) reconstruction is indicative of a Te terminated surface. At higher temperatures, Te is easily evaporated and the Cd sticking coefficient becomes very small,\textsuperscript{5} which considerably reduces the CdTe growth rate, as reported by Sivananthan \textit{et al.}\textsuperscript{6}

RHEED observations clearly show that during CdTe growth at 330°C and after cooling the film from 330 to 200°C, the (2×2) reconstruction patterns were almost identical to that of an epilayer in a Cd environment at 100°C. If the film is kept in a Cd environment at room temperature, additional spots superimposed on the streaks appear. This indicates that a pure Cd film is being deposited, which was confirmed by XPS measurements. A Cd flux of 5×10$^{-7}$ Torr was employed.

The above smooth (2×2) reconstruction cannot be destroyed by heating at temperatures ranging from room temperature to 300°C. If the film is held at temperatures higher than 300°C, half-order reconstruction in the [011] azimuth is still present even though the RHEED patterns are modulated. XPS measurements indicated that the surface was terminated by Cd atoms. In this experiment, we turned off all heating elements with the exception of the substrate heater in order to eliminate as far as possible any partial pressures due to Cd or Te. These experimental results demonstrate that Cd remains on the (111)A CdTe surface when CdTe is sublimed from an (111)A face.

The RHEED pattern of an epilayer in a Te environment at 110°C displays a (1×1) reconstruction. At higher temperatures, 230°C, for example, this (1×1) reconstruction was very easily destroyed if the Te flux is less than 3×10$^{-7}$ Torr. The surface structure changes from a (1×1) to a (2×2) reconstruction and cannot be recovered if a Te flux is not present. This means that a Te stabilized surface requires a Te partial pressure. However, if a (1×1) Te terminated surface is placed in a Cd environment, the RHEED patterns immediately change to a (2×2) and never to a (1×1) reconstruction. We have also kept a substrate with a (1×1) surface reconstruction in the growth chamber for 4 h at room temperature and found no change in the RHEED patterns. Thus, there is no residual Cd partial pressure in the growth chamber which could change the Te stabilized surface for the conditions mentioned above.

We could not measure the Cd activation energy from the (111)A CdTe face with our method because the (2×2) Cd stabilized surface structure could not be changed during heating. The determination of the Te activation energy from the (111)A surface is described below.

First, we very carefully heat treated the (111)A Cd$_{0.96}$Zn$_{0.04}$Te substrates at 180°C which displayed very distinct RHEED patterns. Then, the substrate temperature was raised to 340°C in about 10 min and CdTe was grown for 1 h at 330°C. If either additional dots appear on the original streaks, off angle streaks appear, facets are present\textsuperscript{6} or the (111)A surface becomes wavy as the epilayer thickness is increased, then further growth will not result in an improvement in the structural quality. Because the Te lifetime on the (111)A surface is influenced by the surface structure,\textsuperscript{4,5} a high quality surface as judged by the RHEED patterns is an essential prerequisite for this experiment. After growing a 1-μm-thick CdTe film, we cooled the substrate to the desired experimental temperature between 150 and 210°C. Then, the Te oven was opened for several tens of seconds until smooth (1×1) streaks were obtained. Excess Te atoms on the Te terminated surface was avoided, which would have made the RHEED pattern darker and then produced additional lines. The Te lifetime on the Te stabilized surface was considered to be the persistence time of the (1×1) RHEED pattern after closing the Te shutter and the main shutter. The disappearance of the (1×1) reconstruction was determined by the appearance of a clear half-order reconstruction in the [011] azimuth. The Te converge on the (111)A face was about 80% as was determined by XPS measurements, when a clear half-order reconstruction appeared. The persistence time measurements were repeatable with an error of about 10%. The experimental dependence of the Te desorption time on the inverse of the substrate temperature is shown in Fig. 1. Using the Arrhenius formula, Eq. (1), we determined the Te activation energy for the Te stabilized (111)A CdTe surface to be 1.41±0.10 eV.
FIG. 1. Measured values of the Te surface lifetime on (111)A CdTe. From these measurements, the activation energy for Te was determined to be 1.41 ± 0.10 eV.

In conclusion, we have experimentally shown that Te atoms are removed much easier from the (111)A CdTe surface than is Cd. The Te activation energy is 1.41 ± 0.10 eV, which is much less than the calculated value for sublimation energy.1,2 This discrepancy between experiment and theory is probably due to the influence of surface reconstruction which was not included in the theoretical calculations. These results indicate that surface reconstruction could potentially have considerable influence on the surface properties and should be included in surface sublimation calculations.

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